

Figure 1a

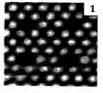


Figure 1b

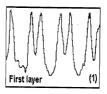


Figure 1c

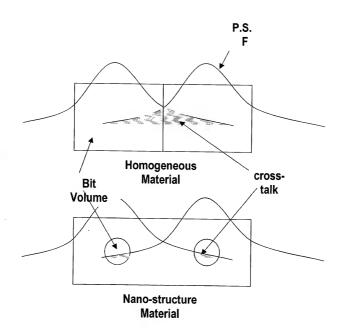


Figure 2. Nanostructured materials significantly reduce the cross-talk in the writing and reading processes by spatial isolation/separation of the active cores.

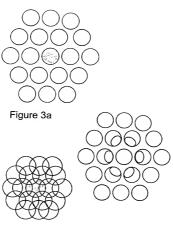


Figure 3b(i) Figure 3 b (ii)

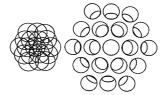


Fig 3c(i) Fig 3c(ii

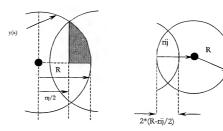


Figure 4a: Definitions of r, the spacin between the bits, and R, the radius o the diffraction pattern.

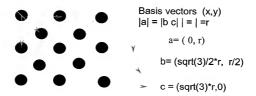


Figure 4b: Basis vectors and o the Lattice Translations

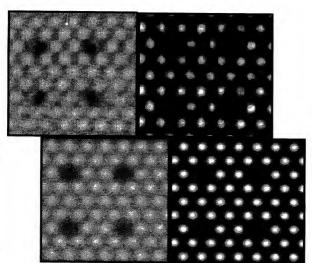


Figure 5 (top left) Laser confocal fluorescent microscopy image of nano-particle array. The bits have core diameter 650 ± 20 nm and shell thickness 200 ± 5 nm. $\lambda_{\text{Phoessoree}} \sim 500$ nm, $\lambda_{\text{two-photon}} = 844$ nm. Resolution is approximately 256x256 samples. A data pattern has been photo-bleached into material (top right) After filtering and deconvolution approximate Gaussian point spread function. (botttom right) simulation of equivalent data with a sine squared basis bit (bottom left) with simulated point-spread function of diameter, 750nm and signal to noise ratio of 10.

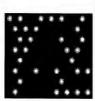


Figure 6a $r \sim \lambda$ Overlap = 0%



Figure 6b r ~ λ/2 Overlap = 50% Rayleigh Limit



Figure 6c r ~ λ/4 Overlap = 75%



Figure 6d $r \sim \lambda/8$ Overlap = 90%

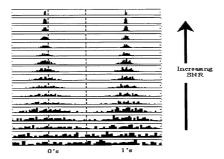
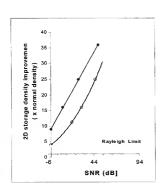


Figure 7: Bit distributions

Figure 8a

Figure 8b



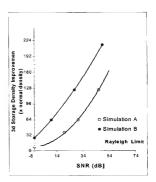


Figure 8c

